

MS23P03

P-Channel 30-V (D-S) MOSFET

Description

The MS23P03 is the highest performance trench P-ch MOSFETs with extreme high cell density, which provide excellent $R_{DS(ON)}$ and gate charge for most of the small power switching and load switch applications. The device meets the RoHS and Green Product requirement with full function reliability approved.

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- Green Device Available

Typical Applications

- Battery Protection
- Load Switch
- Hand-held Instrument

Package type : SOT-23

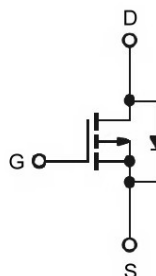
Packing & Order Information

3,000/Reel

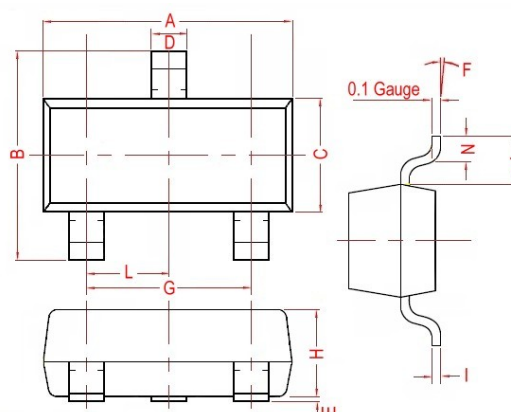


RoHS Compliant

Graphic Symbol

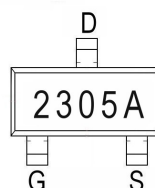


Package Dimension



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	2.70	3.10	G	1.90 Ref.	
B	2.30	3.00	H	0.90	1.30
C	1.20	1.75	I	0.05	0.21
D	0.30	0.50	J	0.58 Ref.	
E	0.01	0.15	L	0.95 Typ.	
F	0°	10°	N	0.20 Min.	

Marking



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MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (unless otherwise specified)

Symbol	Parameter	Value	Units
V_{DS}	Drain-Source Voltage	-30	V
V_{GS}	Gate-Source Voltage	± 12	V
I_D	Continuous Drain Current ($T_A = 25^\circ\text{C}$)	-3.2	A
	Continuous Drain Current ($T_A = 70^\circ\text{C}$)	-2.6	A
I_{DM}	Pulsed Drain Current ² ($T_A = 25^\circ\text{C}$)	-20	A
P_D	Power Dissipation ³ ($T_A = 25^\circ\text{C}$)	1.38	W
T_J/T_{STG}	Operating Junction and Storage Temperature	-55 to +150	$^\circ\text{C}$

Thermal Resistance Ratings

Symbol	Parameter	Maximum	Units
$R_{\theta JA}$	Maximum Junction-to-Ambient ¹	90	$^\circ\text{C/W}$

Electrical Characteristics($T_J = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = -250\mu\text{A}$	-0.5	-	-1.2	V
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0\text{V}$, $I_D = -250\mu\text{A}$	-30	-	-	V
g_{fs}	Forward Transconductance	$V_{DS} = -5\text{V}$, $I_D = -3\text{A}$	-	6	-	S
I_{GSS}	Gate-Source Leakage Current	$V_{DS} = 0\text{V}$, $V_{GS} = \pm 12\text{V}$	-	-	± 100	nA
I_{DSS}	Drain-Source Leakage Current	$V_{DS} = -24\text{V}$, $V_{GS} = 0\text{V}$, $T_J = 25^\circ\text{C}$	-	-	-1	μA
		$V_{DS} = -24\text{V}$, $V_{GS} = 0\text{V}$, $T_J = 55^\circ\text{C}$	-	-	-5	μA
$R_{DS(on)}$	Static Drain-Source On-Resistance ²	$V_{GS} = -10\text{V}$, $I_D = -3.2\text{A}$	-	-	60	m Ω
		$V_{GS} = -4.5\text{V}$, $I_D = -3.0\text{A}$	-	-	80	
		$V_{GS} = -2.5\text{V}$, $I_D = -2.0\text{A}$	-	-	150	
V_{SD}	Diode Forward Voltage ²	$I_S = -1.2\text{A}$, $V_{GS} = 0\text{V}$, $T_J = 25^\circ\text{C}$	-	-	-1.2	V
I_S	Continuous Source Current ^{1,4} (Diode)	$V_G = V_D = 0\text{V}$, Force Current	-	-	-3.2	A

Notes

1. Surface mounted on a 1 inch² FR-4 board with 2OZ copper.
2. The data tested by pulsed, pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.
3. The power dissipation is limited by 150°C junction temperature.
4. The data is theoretically the same as I_D and I_{DM} , in real applications, should be limited by total power dissipation.

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Dynamic and switching Characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
Q _g	Total Gate Charge	V _{DS} = -15V	--	11.9	--	nC
Q _{gs}	Gate-Source Charge	I _D = -3A	--	1.8	--	
Q _{gd}	Gate-Drain Charge	V _{GS} = -4.5V	--	3	--	
t _{d(on)}	Turn-On Delay Time	V _{DS} = -15V	--	6.6	--	ns
t _r	Rise Time	I _D = -3A	--	28	--	
t _{d(off)}	Turn-Off Delay Time	V _{GS} = -4.5V	--	46	--	
t _f	Fall Time	R _G = 3.3Ω	--	21	--	
C _{iss}	Input Capacitance	V _{DS} = -15V	--	920	--	pF
C _{oss}	Output Capacitance	V _{GS} = 0V	--	73	--	
C _{rss}	Reverse Transfer Capacitance	f = 1.0MHz	--	71	--	

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- Typical Electrical Characteristics

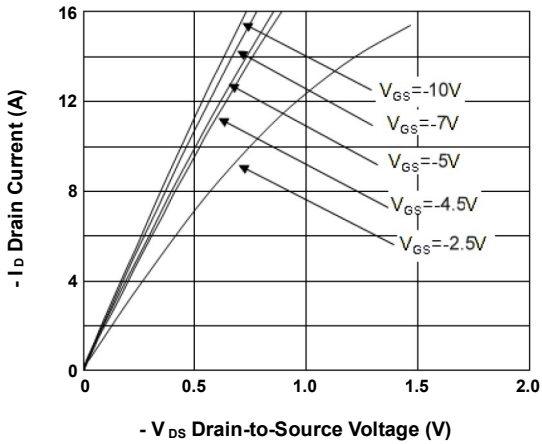


FIG.1-Typical Output Characteristics

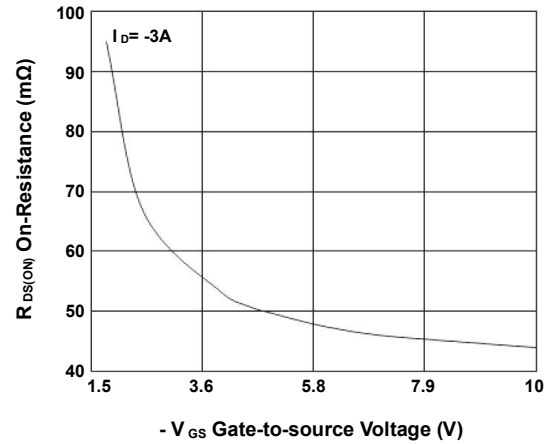


FIG.2-On-Resistance vs. G-S Voltage

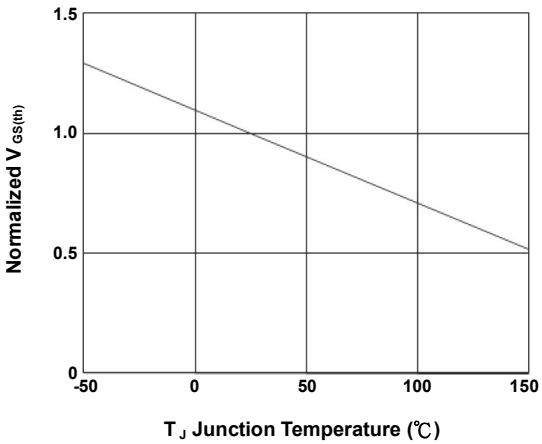


FIG.3-Normalized $V_{GS(th)}$ vs. T_J

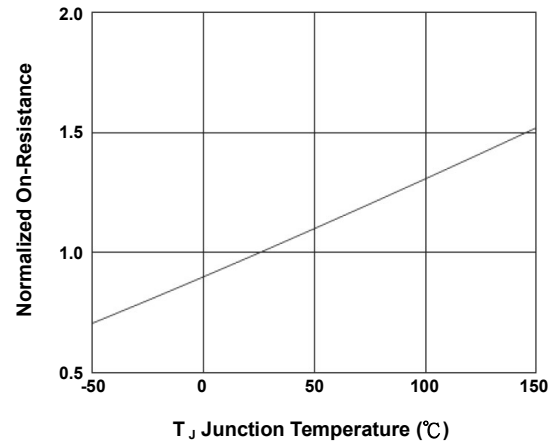


FIG.4-Normalized $R_{DS(on)}$ vs. T_J

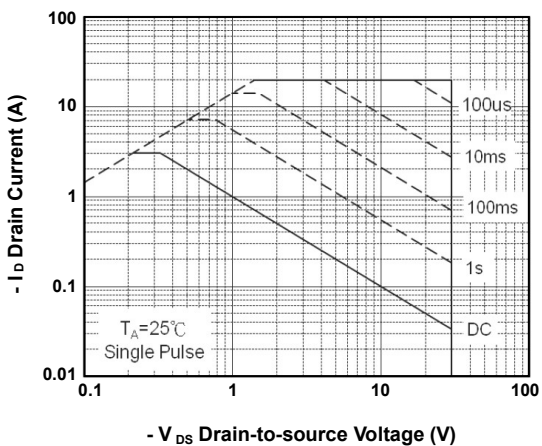


FIG.5-Safe Operating Area

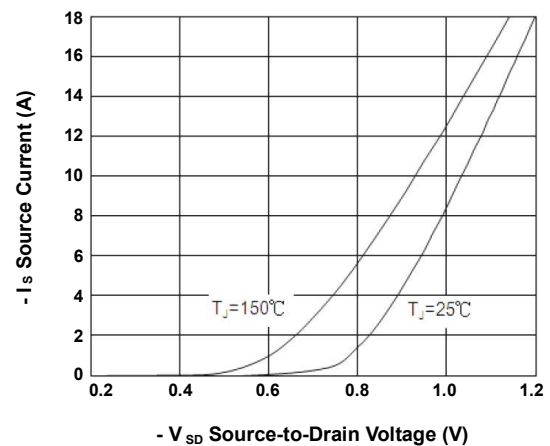


FIG.6-Forward Characteristics of Reverse

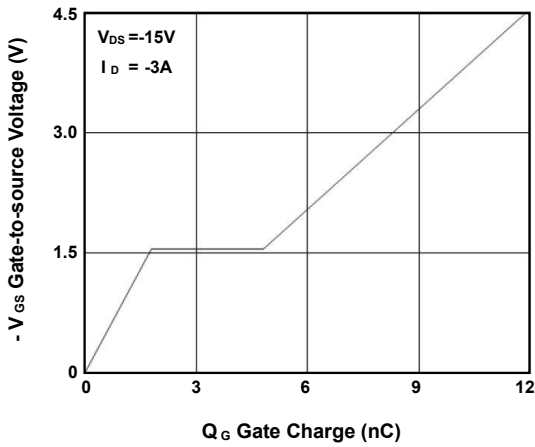


FIG.7-Gate Charge Characteristics

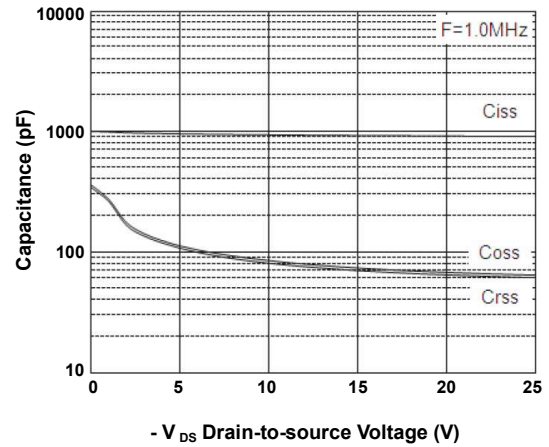


FIG.8-Capacitance Characteristics

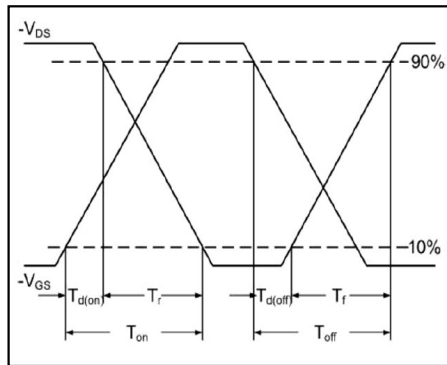


FIG.9-Switching Time Waveform

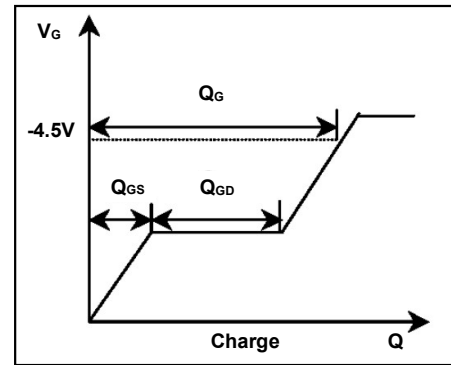


FIG.10-Gate Charge Waveform

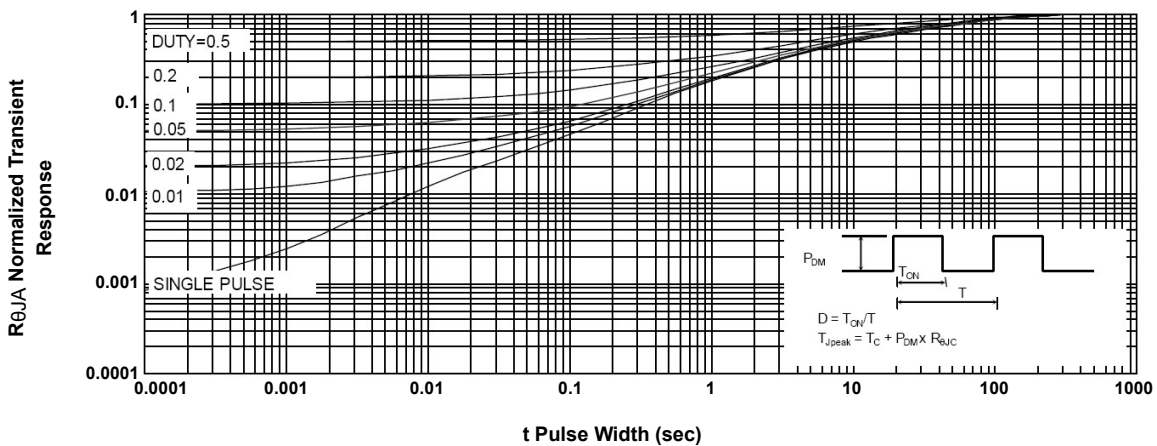


FIG.11-Normalized Maximum Transient Thermal Impedance

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